Complementary Darlington Power Transistor

DPAK For Surface Mount Applications

Designed for general purpose amplifier and low speed switching applications.

Features

- Monolithic Construction With Built-in Base-Emitter Shunt Resistors
- High DC Current Gain: $h_{FE} = 2500$ (Typ) @ $I_C = 4.0$ Adc
- Epoxy Meets UL 94 V-0 @ 0.125 in.
- ESD Ratings:
 - ♦ Human Body Model, 3B > 8000 V
 - ◆ Machine Model, C > 400 V
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These are Pb-Free Devices*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO}	120	Vdc
Collector-Base Voltage	V _{CB}	120	Vdc
Emitter-Base Voltage	V _{EB}	5	Vdc
Collector Current Continuous Peak	l _C	8 16	Adc
Base Current	I _B	120	mAdc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	20 0.16	W/°C
Total Power Dissipation* @ T _A = 25°C Derate above 25°C	P _D	1.75 0.014	W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	6.25	°C/W
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	71.4	°C/W

These ratings are applicable when surface mounted on the minimum pad sizes recommended.



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SILICON POWER TRANSISTOR 8 AMPERES 120 VOLTS, 20 WATTS



DPAK CASE 369C STYLE 1

MARKING DIAGRAM

Base 1	AYWW	
Collector 2 □	J128G	4
Emitter 3 🖂	/	

A = Assembly Location

Y = Year WW = Work Week J128 = Device Code G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
MJD128T4G	DPAK (Pb-Free)	2,500/Tape & Reel
NJVMJD128T4G	DPAK (Pb-Free)	2,500/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage $(I_C = 30 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	120	_	Vdc
Collector Cutoff Current (V _{CE} = 120 Vdc, I _B = 0)	ICEO	_	5	mA
Collector Cutoff Current (V _{CB} = 100 Vdc, I _E = 0)	I _{CBO}	_	10	μAdc
Emitter Cutoff Current (V _{BE} = 5 Vdc, I _C = 0)	I _{EBO}	_	2	mAdc
ON CHARACTERISTICS	<u>.</u>			
DC Current Gain ($I_C = 4$ Adc, $V_{CE} = 4$ Vdc) ($I_C = 8$ Adc, $V_{CE} = 4$ Vdc)	h _{FE}	1000 100	12,000	_
Collector–Emitter Saturation Voltage (I _C = 4 Adc, I _B = 16 mAdc) (I _C = 8 Adc, I _B = 80 mAdc)	V _{CE(sat)}		2 4	Vdc
Base–Emitter Saturation Voltage (1) (I _C = 8 Adc, I _B = 80 mAdc)	V _{BE(sat)}	-	4.5	Vdc
Base–Emitter On Voltage (I _C = 4 Adc, V _{CE} = 4 Vdc)	V _{BE(on)}	_	2.8	Vdc
DYNAMIC CHARACTERISTICS	<u>.</u>			
Current–Gain–Bandwidth Product (I _C = 3 Adc, V _{CE} = 4 Vdc, f = 1 MHz)	h _{fe}	4	_	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 0.1 MHz)	C _{ob}	-	300	pF
Small-Signal Current Gain (I _C = 3 Adc, V _{CE} = 4 Vdc, f = 1 kHz)	h _{fe}	300	-	_

^{2.} Pulse Test: Pulse Width $\leq 300 \,\mu\text{s}$, Duty Cycle $\leq 2\%$.

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

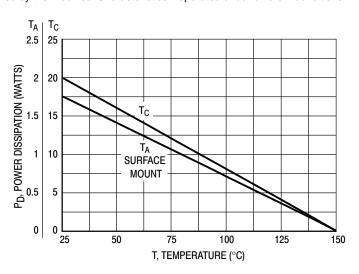


Figure 1. Power Derating

TYPICAL ELECTRICAL CHARACTERISTICS

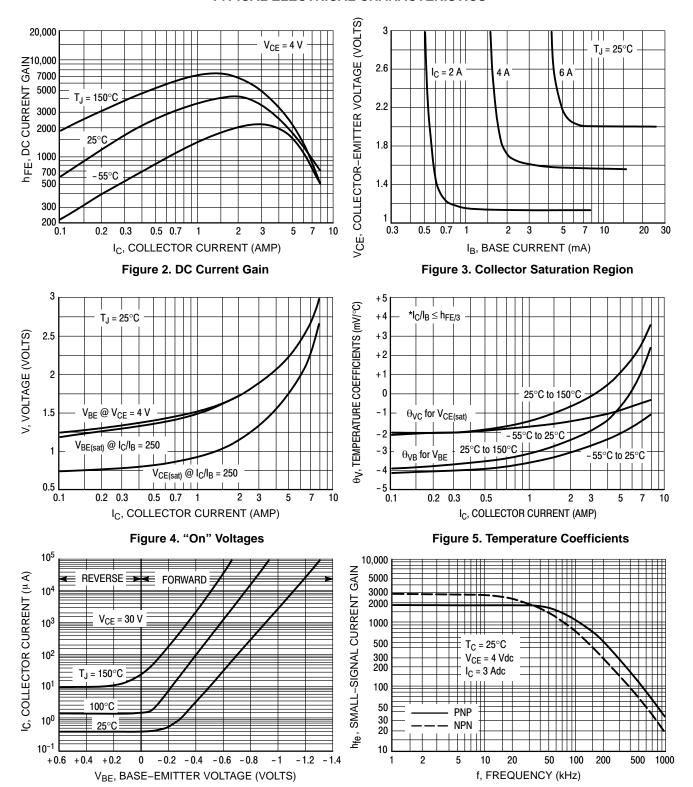


Figure 7. Small-Signal Current Gain

Figure 6. Collector Cut-Off Region

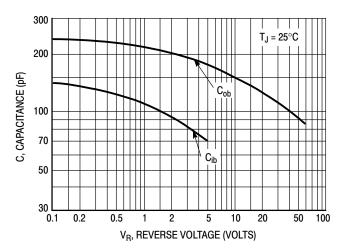


Figure 8. Capacitance

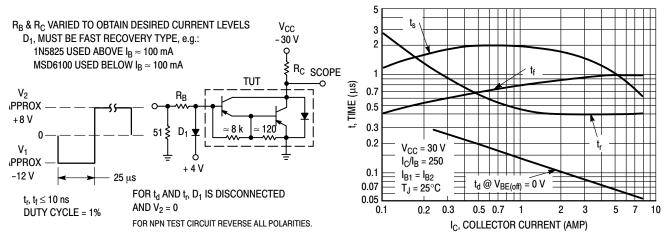


Figure 9. Switching Times Test Circuit

Figure 10. Switching Times

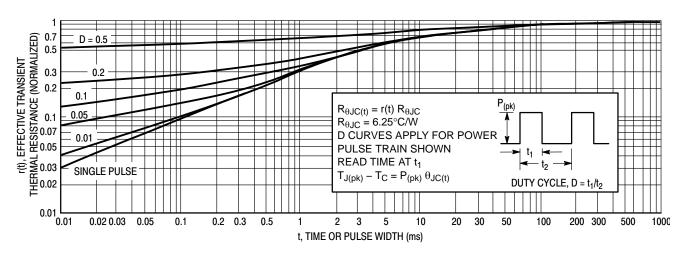


Figure 11. Thermal Response

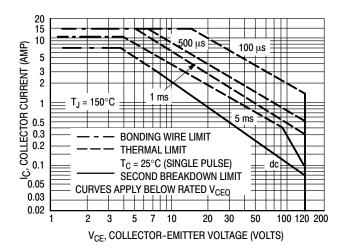


Figure 12. Maximum Forward Bias Safe Operating REA

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 12 is based on $T_{J(pk)} = 150^{\circ}C$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} < 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 11. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

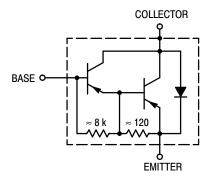
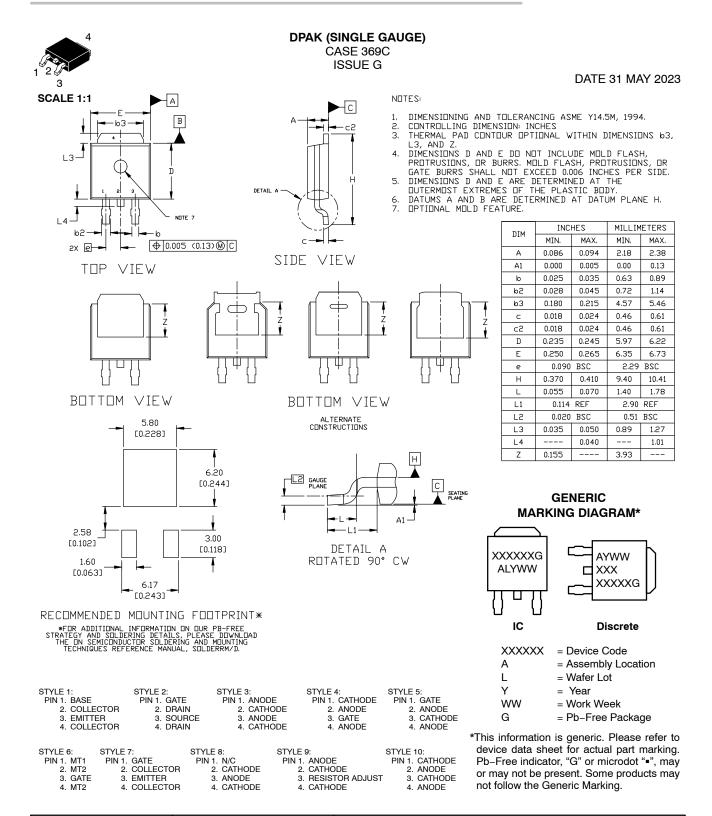


Figure 13. Darlington Schematic





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DESCRIPTION:	DPAK (SINGLE GAUGE)		PAGE 1 OF 1

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